700MHz, Crystal Oscillator-to-Differential LVDS Frequency Synthesizer

ICS8442B

DATA SHEET

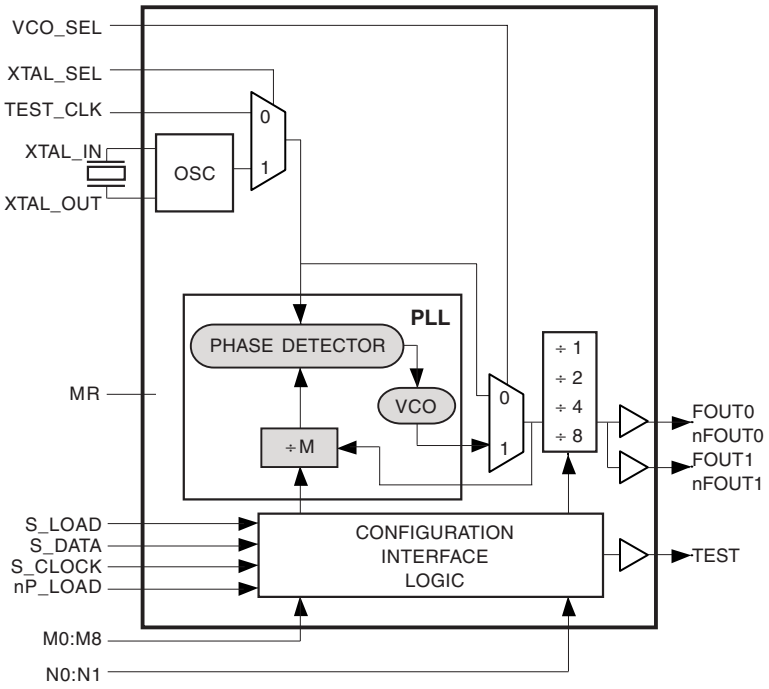
General Description

The ICS8442B is a general purpose, dual output Crystal-to-Differential LVDS High Frequency Synthesizer . The ICS8442B has a selectable TEST_CLK or crystal input. The TEST_CLK input accepts LVCMOS or LVTTL input levels and translates them to LVDS levels. The VCO operates at a frequency range of 250MHz to 700MHz.The VCO frequency is programmed in steps equal to the value of the input reference or crystal frequency. The VCO and output frequency can be programmed using the serial or parallel interface to the configuration logic. The low phase noise characteristics of the ICS8442B makes it an ideal clock source for Gigabit Ethernet and Sonet applications.

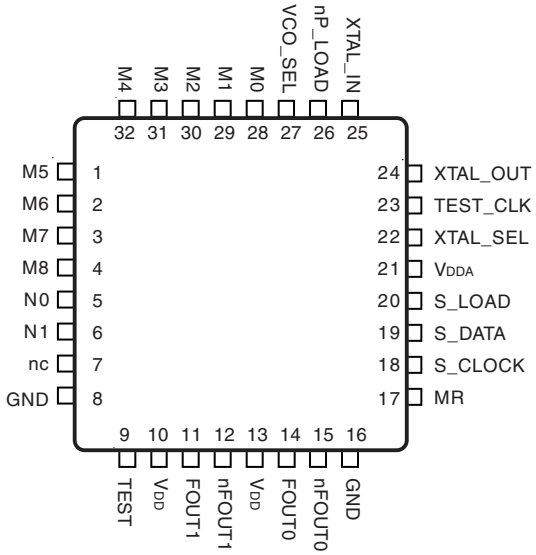
Features

- Dual differential LVDS outputs
- Selectable crystal oscillator interface or LVCMOS/LVTTL TEST_CLK
- Output frequency range: 31.25MHz to 700MHz
- Crystal input frequency range: 10MHz to 25MHz
- VCO range: 250MHz to 700MHz
- Parallel or serial interface for programming counter and output dividers
- RMS period jitter: 2.7ps (typical)
- Cycle-to-cycle jitter: 18ps (typical)
- 3.3V supply voltage
- 0°C to 85°C ambient operating temperature
- Lead-Free package fully RoHS compliant

Block Diagram



Pin Assignment



ICS 8442B
32-Lead LQFP
7mm x 7mm x 1.4mm package body
Y Package
Top View

Functional Description

NOTE: The functional description that follows describes operation using a 25MHz crystal. Valid PLL loop divider values for different crystal or input frequencies are defined in the Input Frequency Characteristics, Table 5, NOTE 1.

The ICS8442B features a fully integrated PLL and therefore requires no external components for setting the loop bandwidth. A fundamental crystal is used as the input to the on-chip oscillator. The output of the oscillator is fed into the phase detector. A 25MHz crystal provides a 25MHz phase detector reference frequency. The VCO of the PLL operates over a range of 250MHz to 700MHz. The output of the M divider is also applied to the phase detector.

The phase detector and the M divider force the VCO output frequency to be M times the reference frequency by adjusting the VCO control voltage. Note that for some values of M (either too high or too low), the PLL will not achieve lock. The output of the VCO is scaled by a divider prior to being sent to each of the LVDS output buffers. The divider provides a 50% output duty cycle.

The programmable features of the ICS8442B support two input modes to program the M divider and N output divider. The two input operational modes are parallel and serial. *Figure 1* shows the timing diagram for each mode. In parallel mode, the nP_LOAD input is initially LOW. The data on inputs M0 through M8 and N0 and N1 is passed directly to the M divider and N output divider. On the LOW-to-HIGH transition of the nP_LOAD input, the data is latched and the M divider remains loaded until the next LOW transition on nP_LOAD or until a serial event occurs. As a result, the M and N bits can be hardwired to set the M divider and N output divider to a specific default state that will automatically occur during power-up. The TEST output is LOW when operating in the parallel input mode. The relationship between the VCO frequency, the crystal frequency and the M divider is defined as follows: **fVCO = fxtal x M**

The M value and the required values of M0 through M8 are shown in Table 3B, Programmable VCO Frequency Function Table. Valid M values for which the PLL will achieve lock for a 25MHz reference are defined as $10 \leq M \leq 28$. The frequency out is defined as follows: $\mathbf{FOUT = \frac{fVCO}{N} = fxtal \times \frac{M}{N}}$

Serial operation occurs when nP_LOAD is HIGH and S_LOAD is LOW. The shift register is loaded by sampling the S_DATA bits with the rising edge of S_CLOCK. The contents of the shift register are loaded into the M divider and N output divider when S_LOAD transitions from LOW-to-HIGH. The M divide and N output divide values are latched on the HIGH-to-LOW transition of S_LOAD. If S_LOAD is held HIGH, data at the S_DATA input is passed directly to the M divider and N output divider on each rising edge of S_CLOCK. The serial mode can be used to program the M and N bits and test bits T1 and T0. The internal registers T0 and T1 determine the state of the TEST output as follows:

T1	T0	TEST Output
0	0	LOW
0	1	S_Data, Shift Register Input
1	0	Output of M divider
1	1	CMOS FOUT

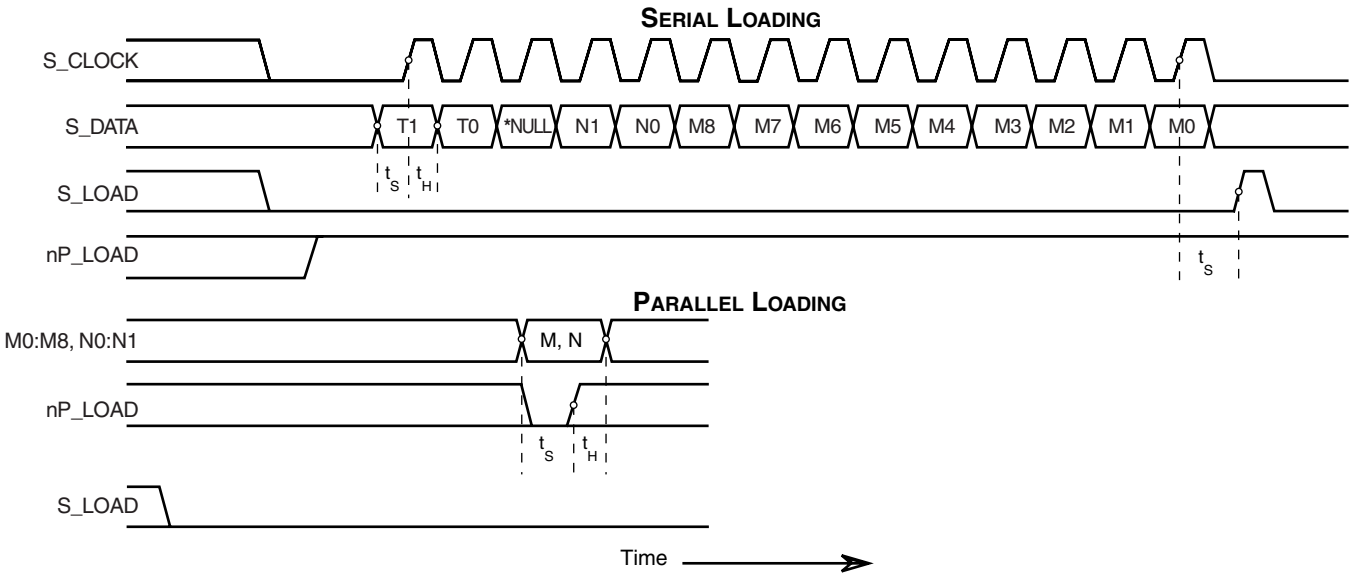


Figure 1. Parallel & Serial Load Operations

***NOTE:** The NULL timing slot must be observed.

TABLE 1. PIN DESCRIPTIONS

Number	Name	Type		Description
1	M5	Input	Pullup	M divider inputs. Data latched on LOW-to-HIGH transistion of nP_LOAD input. LVCMOS / LVTTL interface levels.
2, 3, 4, 28, 29, 30, 31, 32	M6, M7, M8, M0, M1, M2, M3, M4	Input	Pulldown	
5, 6	N0, N1	Input	Pulldown	Determines output divider value as defined in Table 3C Function Table. LVCMOS / LVTTL interface levels.
7	nc	Unused		No connect.
8, 16	GND	Power		Power supply ground.
9	TEST	Output		Test output which is ACTIVE in the serial mode of operation. Output driven LOW in parallel mode. LVCMOS / LVTTL interface levels.
10, 13	V_{DD}	Power		Core supply pins.
11, 12	FOUT1, nFOUT1	Output		Differential output for the synthesizer. LVDS interface levels.
14, 15	FOUT0, nFOUT0	Output		Differential output for the synthesizer. LVDS interface levels.
17	MR	Input	Pulldown	Active High Master Reset. When logic HIGH, the internal dividers are reset causing the true outputs FOUTx to go low and the inverted outputs nFOUTx to go high. When logic LOW, the internal dividers and the outputs are enabled. Assertion of MR does not effect loaded M, N, and T values. LVCMOS / LVTTL interface levels.
18	S_CLOCK	Input	Pulldown	Clocks in serial data present at S_DATA input into the shift register on the rising edge of S_CLOCK. LVCMOS / LVTTL interface levels.
19	S_DATA	Input	Pulldown	Shift register serial input. Data sampled on the rising edge of S_CLOCK. LVCMOS / LVTTL interface levels.
20	S_LOAD	Input	Pulldown	Controls transition of data from shift register into the dividers. LVCMOS / LVTTL interface levels.
21	V_{DDA}	Power		Analog supply pin.
22	XTAL_SEL	Input	Pullup	Selects between crystal oscillator or test inputs as the PLL reference source. Selects XTAL inputs when HIGH. Selects TEST_CLK when LOW. LVCMOS / LVTTL interface levels.
23	TEST_CLK	Input	Pulldown	Test clock input. LVCMOS / LVTTL interface levels.
24, 25	XTAL_IN, XTAL_OUT	Input		Crystal oscillator interface. XTAL_IN is the input, XTAL_OUT is the output.
26	nP_LOAD	Input	Pulldown	Parallel load input. Determines when data present at M8:M0 is loaded into M divider, and when data present at N1:N0 sets the N output divider value. LVCMOS / LVTTL interface levels.
27	VCO_SEL	Input	Pullup	Determines whether synthesizer is in PLL or bypass mode. LVCMOS / LVTTL interface levels.

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance			4		pF
R_{PULLUP}	Input Pullup Resistor			51		kΩ
$R_{PULLDOWN}$	Input Pulldown Resistor			51		kΩ

TABLE 3A. PARALLEL AND SERIAL MODE FUNCTION TABLE

Inputs							Conditions
MR	nP_LOAD	M	N	S_LOAD	S_CLOCK	S_DATA	
H	X	X	X	X	X	X	Reset. When HIGH, forces the outputs to a differential LOW state (FOUTx = LOW and nFOUTx = HIGH), but does not effect loaded M, N, and T values.
L	L	Data	Data	X	X	X	Data on M and N inputs passed directly to the M divider and N output divider. TEST output forced LOW.
L	↑	Data	Data	L	X	X	Data is latched into input registers and remains loaded until next LOW transition or until a serial event occurs.
L	H	X	X	L	↑	Data	Serial input mode. Shift register is loaded with data on S_DATA on each rising edge of S_CLOCK.
L	H	X	X	↑	L	Data	Contents of the shift register are passed to the M divider and N output divider.
L	H	X	X	↓	L	Data	M divider and N output divider values are latched.
L	H	X	X	L	X	X	Parallel or serial input do not affect shift registers.
L	H	X	X	H	↑	Data	S_DATA passed directly to M divider as it is clocked.

NOTE: L = LOW
H = HIGH
X = Don't care
↑ = Rising edge transition
↓ = Falling edge transition

TABLE 3B. PROGRAMMABLE VCO FREQUENCY FUNCTION TABLE

VCO Frequency (MHz)	M Divide	256	128	64	32	16	8	4	2	1
		M8	M7	M6	M5	M4	M3	M2	M1	M0
250	10	0	0	0	0	0	1	0	1	0
275	11	0	0	0	0	0	1	0	1	1
•	•	•	•	•	•	•	•	•	•	•
•	•	•	•	•	•	•	•	•	•	•
650	26	0	0	0	0	1	1	0	1	0
675	27	0	0	0	0	1	1	0	1	1
700	28	0	0	0	0	1	1	1	0	0

NOTE 1: These M divide values and the resulting frequencies correspond to crystal or TEST_CLK input frequency of 25MHz.

TABLE 3C. PROGRAMMABLE OUTPUT DIVIDER FUNCTION TABLE

Inputs		N Divider Value	Output Frequency (MHz)	
N1	N0		Minimum	Maximum
0	0	1	250	700
0	1	2	125	350
1	0	4	62.5	175
1	1	8	31.25	87.5

Absolute Maximum Ratings

Supply Voltage, V_{DD}	4.6V
Inputs, V_I	-0.5V to V_{DD} + 0.5V
Outputs, I_O	
Continuous Current	10mA
Surge Current	15mA
Package Thermal Impedance, θ_{JA}	47.9°C/W (0 lfpm)
Storage Temperature, T_{STG}	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 4A. Power Supply DC Characteristics, V_{DD} = 3.3V±5%, T_A = 0°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V_{DDA}	Analog Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				182	mA
I_{DDA}	Analog Supply Current				16	mA

Table 4B. LVCMOS / LVTTL DC Characteristics, V_{DD} = 3.3V±5%, T_A = 0°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	M0-M8, N0, N1, MR, nP_LOAD, S_CLOCK, S_DATA, S_LOAD, XTAL_SEL, VCO_SEL		2		V_{DD} + 0.3	V
		TEST_CLK		2		V_{DD} + 0.3	V
V_{IL}	Input Low Voltage	M0-M8, N0, N1, MR, nP_LOAD, S_CLOCK, S_DATA, S_LOAD, XTAL_SEL, VCO_SEL		-0.3		0.8	V
		TEST_CLK		-0.3		1.3	V
I_{IH}	Input High Current	M0-M4, M6-M8, N0, N1, MR, nP_LOAD, S_CLOCK, S_DATA, S_LOAD,	V_{DD} = V_{IN} = 3.465V			150	µA
		M5, XTAL_SEL, VCO_SEL	V_{DD} = V_{IN} = 3.465V			5	
I_{IL}	Input Low Current	M0-M4, M6-M8, N0, N1, MR, nP_LOAD, S_CLOCK, S_DATA, S_LOAD,	V_{DD} = 3.465V, V_{IN} = 0V	-5			µA
		M5, XTAL_SEL, VCO_SEL	V_{DD} = 3.465V, V_{IN} = 0V	-150			
V_{OH}	Output High Voltage	TEST; NOTE 1		2.6			V
V_{OL}	Output Low Voltage	TEST; NOTE 1				0.5	V

NOTE 1: Outputs terminated with 50Ω to V_{DD}/2. See Parameter Measurement Information section, "3.3V Output Load Test Circuit".

Table 4C. LVDS DC Characteristics, V_{DD} = 3.3V±5%, T_A = 0°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{OD}	Differential Output Voltage		250	450	600	mV
ΔV_{OD}	V_{OD} Magnitude Change				50	mV
V_{OS}	Offset Voltage		1.125	1.4	1.6	V
ΔV_{OS}	V_{OS} Magnitude Change				50	mV

TABLE 5. INPUT FREQUENCY CHARACTERISTICS, V_{DD} = 3.3V±5%, TA = 0°C TO 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f_{IN}	Input Frequency	TEST_CLK; NOTE 1		10		25	MHz
		XTAL_IN, XTAL_OUT; NOTE 1		10		25	MHz
		S_CLOCK				50	MHz

NOTE 1: For the input crystal and TEST_CLK frequency range the M value must be set for the VCO to operate within the 250MHz to 700MHz range. Using the minimum input frequency of 10MHz valid values of M are 25 ≤ M ≤ 70. Using the maximum frequency of 25MHz valid values of M are 10 ≤ M ≤ 28.

TABLE 6. CRYSTAL CHARACTERISTICS

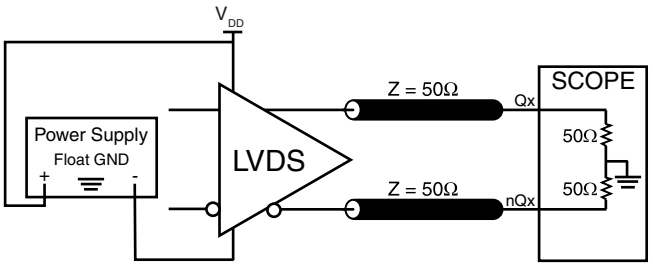
Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency		10		25	MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF
Drive Level				1	mW

TABLE 7. AC CHARACTERISTICS, V_{DD} = 3.3V±5%, TA = 0°C TO 85°C

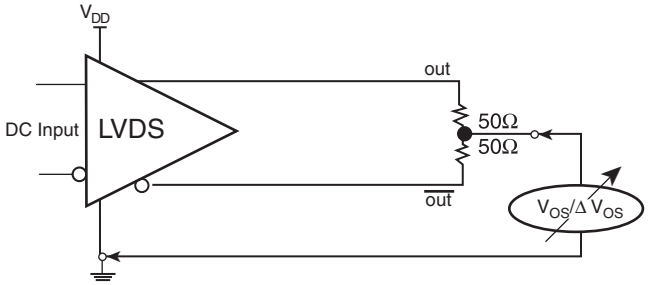
Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
F_{OUT}	Output Frequency			31.25		700	MHz
*t*jit(cc)	Cycle-to-Cycle Jitter; NOTE 1, 3		N = 1, 2		18	28	ps
			N = 4		27	45	ps
*t*jit(per)	Period Jitter, RMS; NOTE 1, 3				2.7	7	ps
*t*sk(o)	Output Skew; NOTE 2, 3					15	ps
t_R / t_F	Output Rise/Fall Time		20% to 80%	150		650	ps
t_S	Setup Time	M, N to nP_LOAD		5			ns
		S_DATA to S_CLOCK		5			ns
		S_CLOCK to S_LOAD		5			ns
t_H	Hold Time	M, N to nP_LOAD		5			ns
		S_DATA to S_CLOCK		5			ns
		S_CLOCK to S_LOAD		5			ns
odc	Output Duty Cycle; NOTE 4		N > 1	48		52	%
t_{PW}	Output Pulse Width		N = 1	$t_{Period}/2$ - 150		$t_{Period}/2$ + 150	ps
t_{LOCK}	PLL Lock Time					1	ms

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
NOTE: See Parameter Measurement Information section.
NOTE 1: Jitter performance using XTAL inputs.
NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.
Measured at the output differential cross points.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 4: In the Applications Section, please refer to the application note, "Differential Duty Cycle Improvement."

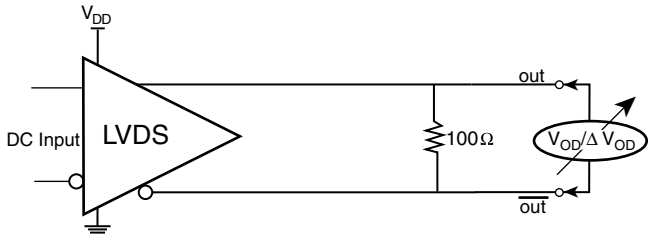
PARAMETER MEASUREMENT INFORMATION



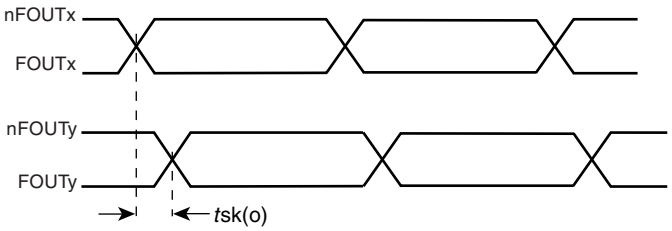
3.3V OUTPUT LOAD TEST CIRCUIT



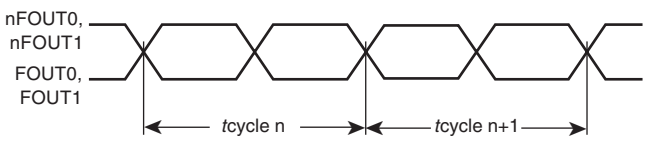
OFFSET VOLTAGE SETUP



DIFFERENTIAL OUTPUT VOLTAGE SETUP

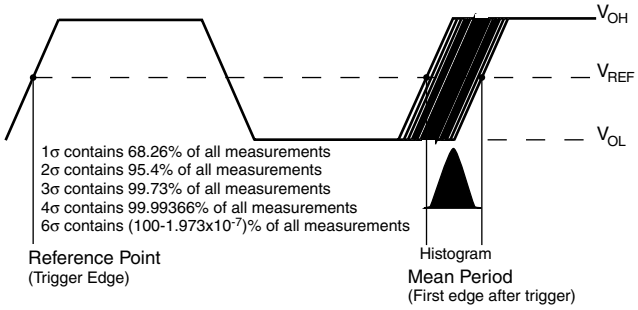


OUTPUT SKEW

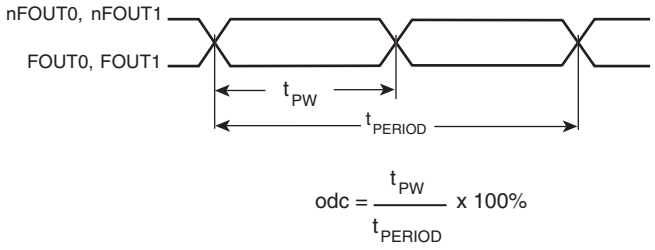


$t_{jit(cc)} = t_{cycle\ n} - t_{cycle\ n+1}$
1000 Cycles

Cycle-to-Cycle Jitter

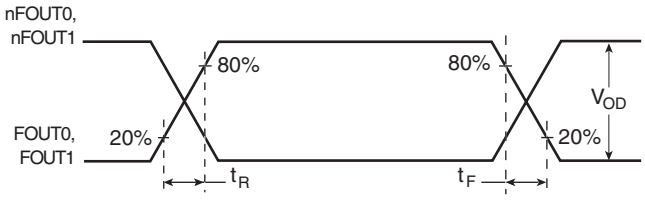


Period Jitter



$$odc = \frac{t_{PW}}{t_{PERIOD}} \times 100\%$$

OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD



OUTPUT RISE/FALL TIME

APPLICATION INFORMATION

STORAGE AREA NETWORKS

A variety of technologies are used for interconnection of the elements within a SAN. The tables below lists the common frequencies used as well as the settings for the ICS8442B to generate the appropriate frequency.

Table 8. Common SANs Application Frequencies

Interconnect Technology	Clock Rate	Reference Frequency to SERDES (MHz)	Crystal Frequency (MHz)
Gigabit Ethernet	1.25 GHz	125, 250, 156.25	25, 19.53125
Fibre Channel	FC1 1.0625 GHz FC2 2.1250 GHz	106.25, 53.125, 132.8125	16.6015625, 25
Infiniband	2.5 GHz	125, 250	25

Table 9. Configuration Details for SANs Applications

Interconnect Technology	Crystal Frequency (MHz)	ICS8442B Output Frequency to SERDES (MHz)	ICS8442B M & N Settings										
			M8	M7	M6	M5	M4	M3	M2	M1	M0	N1	N0
Gigabit Ethernet	25	125	0	0	0	0	1	0	1	0	0	1	0
	25	250	0	0	0	0	1	0	1	0	0	0	1
	25	156.25	0	0	0	0	1	1	0	0	1	1	0
	19.53125	156.25	0	0	0	1	0	0	0	0	0	1	0
Fiber Channel 1	25	53.125	0	0	0	0	1	0	0	0	1	1	1
	25	106.25	0	0	0	0	1	0	0	0	1	1	0
Fiber Channel 2	16.6015625	132.8125	0	0	0	1	0	0	0	0	0	1	0
Infiniband	25	125	0	0	0	0	1	0	1	0	0	1	0
	25	250	0	0	0	0	1	0	1	0	0	0	1

POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The ICS8442B provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{DD} and V_{DDA}, should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, better power supply isolation is required. *Figure 2* illustrates how a 10Ω along with a 10µF and a .01µF bypass capacitor should be connected to each V_{DDA} pin.

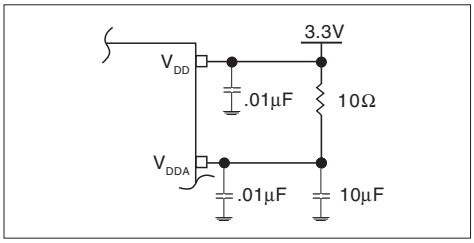


FIGURE 2. POWER SUPPLY FILTERING

Crystal Input Interface

A crystal can be characterized for either series or parallel mode operation. The ICS8442B has a built-in crystal oscillator circuit. This interface can accept either a series or parallel crystal without additional components and generate frequencies with accuracy suitable for most applications. Additional accuracy can be achieved by adding two small capacitors C1 and C2 as shown in *Figure 3*. Typical results using parallel 18pF crystals are shown in Table 10.

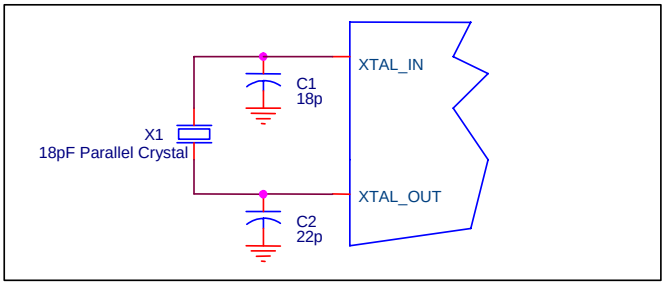


Figure 3. Crystal Input Interface

LVDS Driver Termination

A general LVDS interface is shown in *Figure 4.* In a 100Ω differential transmission line environment, LVDS drivers require a matched load termination of 100Ω across near the receiver input. For a multiple LVDS outputs buffer, if only partial outputs are used, it is recommended to terminate the un-used outputs.

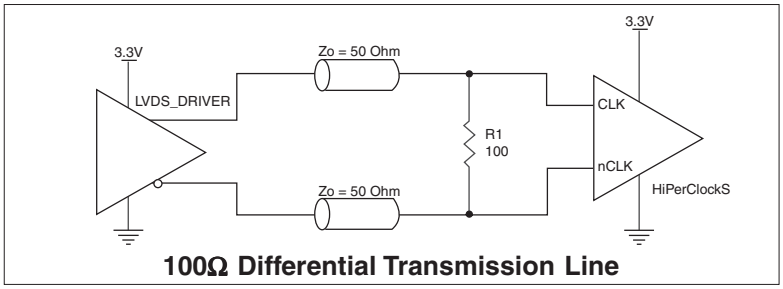


Figure 4. Typical LVDS Driver Termination

Differential Duty Cycle Improvement

The schematic below is recommended for applications using the ÷1 output configuration for improving the differential duty cycle.

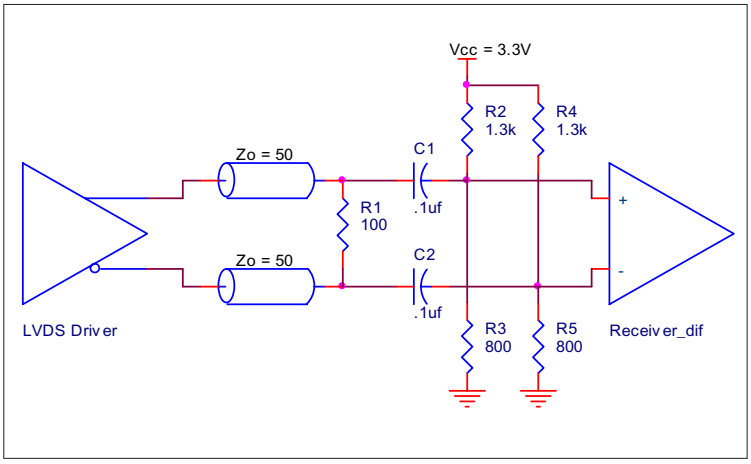


Figure 5. Differential Duty Cycle Improvement

Layout Guideline

The schematic of the ICS8442B layout example used in this layout guideline is shown in *Figure 6A*. The ICS8442B recommended PCB board layout for this example is shown in *Figure 6B*. This layout example is used as a general guideline. The layout in the actual system will depend on the selected component types, the density of the components, the density of the traces, and the stack up of the P.C. board.

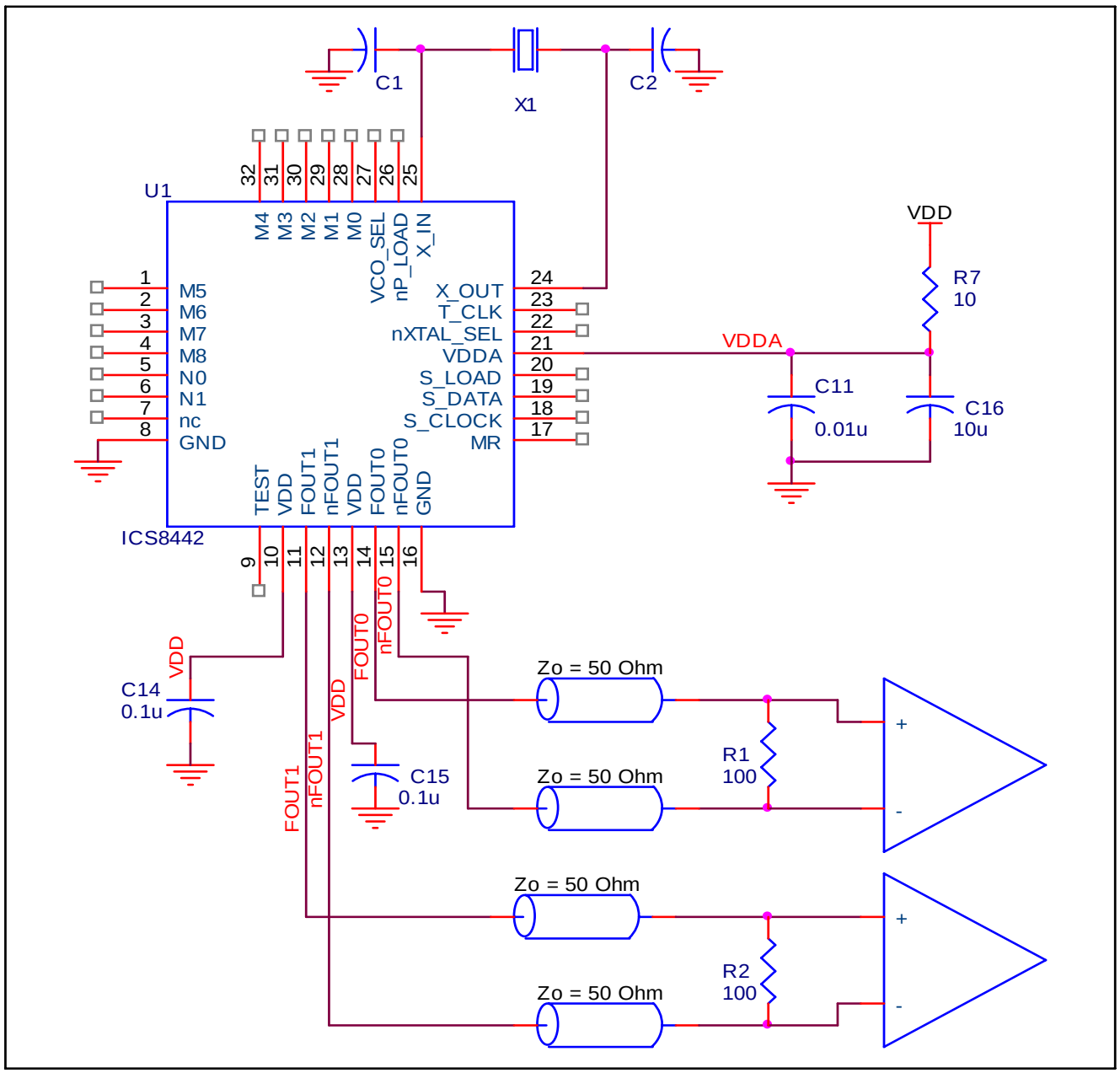


Figure 6A. Recommended Schematic Layout

The following component footprints are used in this layout example: All the resistors and capacitors are size 0603.

Power and Grounding

Place the decoupling capacitors C14 and C15 as close as possible to the power pins. If space allows, placing the decoupling capacitor at the component side is preferred. This can reduce unwanted inductance between the decoupling capacitor and the power pin generated by the via.

Maximize the pad size of the power (ground) at the decoupling capacitor. Maximize the number of vias between power (ground) and the pads. This can reduce the inductance between the power (ground) plane and the component power (ground) pins.

If V_{DDA} shares the same power supply with V_{DD}, insert the RC filter R7, C11, and C16 in between. Place this RC filter as close to the V_{DDA} as possible.

Clock Traces and Termination

The component placements, locations and orientations should be arranged to achieve the best clock signal quality. Poor clock signal quality can degrade the system performance or cause system failure. In the synchronous high-speed digital system, the clock signal is less tolerable to poor signal quality than other signals. Any ringing on the rising or falling edge or excessive ring back can cause system failure. The trace shape and the trace delay might be restricted by the available space on the board and the component location. While routing the traces, the clock signal traces should be routed first and should be locked prior to routing other signal traces.

- The traces with 50Ω transmission lines TL1 and TL2 at FOUT and nFOUT should have equal delay and run adjacent to each other. Avoid sharp angles on the clock trace. Sharp angle turns cause the characteristic impedance to change on the transmission lines.
- Keep the clock trace on same layer. Whenever possible, avoid any vias on the clock traces. Any via on the trace can affect the trace characteristic impedance and hence degrade signal quality.
- To prevent cross talk, avoid routing other signal traces in parallel with the clock traces. If running parallel traces is unavoidable, allow more space between the clock trace and the other signal trace.
- Make sure no other signal trace is routed between the clock trace pair.

The matching termination resistors R1 and R2 should be located as close to the receiver input pins as possible. Other termination scheme can also be used but is not shown in this example.

Crystal

The crystal X1 should be located as close as possible to the pins 24 (XTAL_OUT) and 25 (XTAL_IN). The trace length between the X1 and U1 should be kept to a minimum to avoid unwanted parasitic inductance and capacitance. Other signal traces should not be routed near the crystal traces.

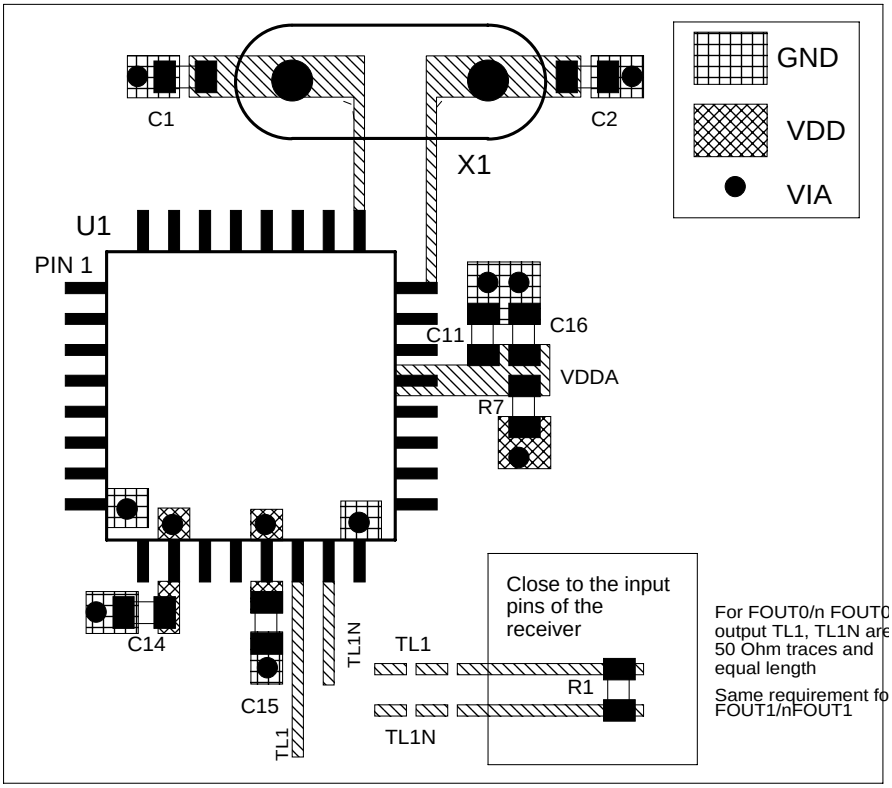


Figure 6B. PCB Board Layout for ICS8442

RELIABILITY INFORMATION

TABLE 10. θ_{JA} VS. AIR FLOW TABLE FOR 32 LEAD LQFP

θ_{JA} by Velocity (Linear Feet per Minute)			
	0	**200**	**500**
Single-Layer PCB, JEDEC Standard Test Boards	67.8°C/W	55.9°C/W	50.1°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	47.9°C/W	42.1°C/W	39.4°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TRANSISTOR COUNT

The transistor count for ICS8442B is: 3662

Package Outline - Y Suffix for 32 Lead LQFP

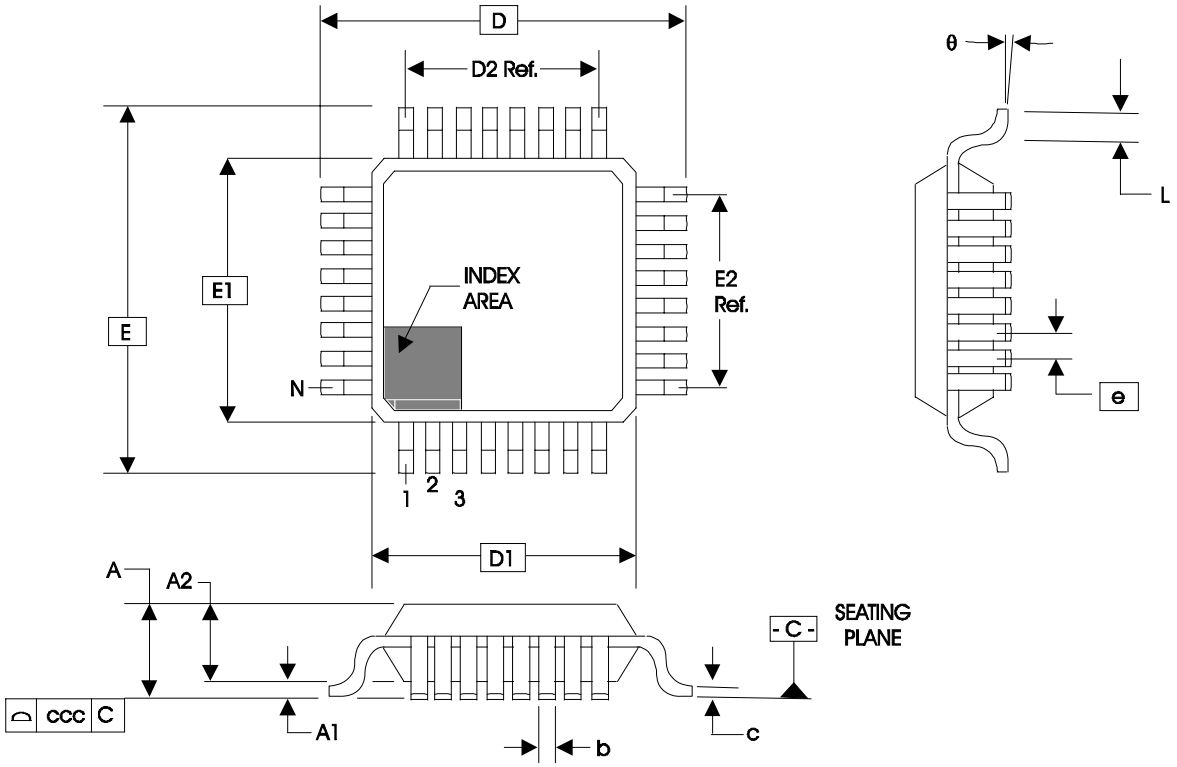


Table 11. Package Dimensions

JEDEC VARIATION ALL DIMENSIONS IN MILLIMETERS			
SYMBOL	BBA		
	MINIMUM	NOMINAL	MAXIMUM
N		32	
A	--	--	1.60
A1	0.05	--	0.15
A2	1.35	1.40	1.45
b	0.30	0.37	0.45
c	0.09	--	0.20
D		9.00 BASIC	
D1		7.00 BASIC	
D2		5.60 Ref.	
E		9.00 BASIC	
E1		7.00 BASIC	
E2		5.60 Ref.	
e		0.80 BASIC	
L	0.45	0.60	0.75
θ	0°	--	7°
ccc	--	--	0.10

Reference Document: JEDEC Publication 95, MS-026

TABLE 12. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
8442BYLF	ICS8442BYLF	32 lead "Lead Free" LQFP	Tray	0°C to +85°C
8442BYLFT	ICS8442BYLF	32 lead "Lead Free" LQFP	Tape and Reel	0°C to +85°C

REVISION HISTORY SHEET				
Rev	**Table**	**Page**	**Description of Change**	**Date**
A	T4A T12	5 14	Per PCN: N1308-01 Effective date 1/31/2014 Changed part number from ICS8442 to ICS8442B throughout the datasheet. Power Supply DC Characteristics Table - changed I_{DD} spec from 155mA max. to 182mA max; and changed I_{DDA} spec from 20mA max. to 16mA max. Ordering Information Table - changed ordering information and marking revision from "A" to "B". Deleted leaded part information.	11/18/13

IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES (“RENESAS”) PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers who are designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only to develop an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third-party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising from your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Disclaimer Rev.1.01 Jan 2024)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit www.renesas.com/contact-us/.

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.